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## ESD5V0D3B

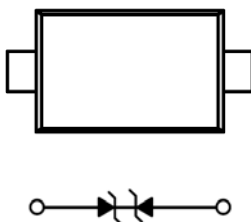
### Features

- For sensitive ESD protection
- Low clamping voltage
- Low leakage
- Protects one power or I/O port
- ESD protection > 35 kV
- Fast response ,response time less than 1ns.  
Epoxy meets UL 94 V-0 flammability rating  
Moisture Sensitivity Level 1

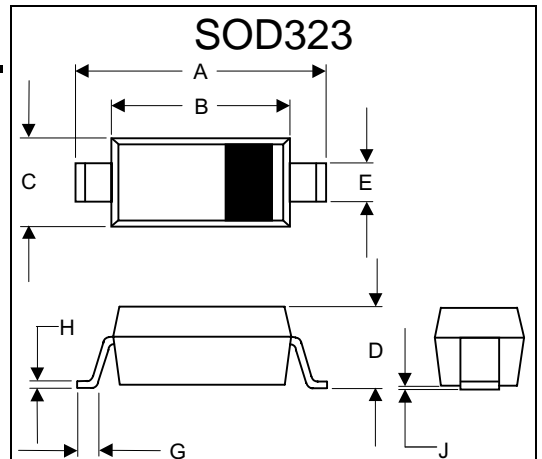
### Maximum Ratings

- Operating Junction & Storage Temperature: -55°C to +150°C

Parameter	Symbol	Limits	unit
IEC61000-4-2(ESD) Air Contact		$\pm 15$ $\pm 8$	KV
IEC 61000-4-4 (EFT) (5/50ns)		40	A
Power Dissipation	Ppp	500	W

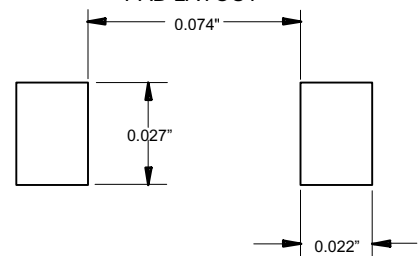


## 5.0Volts ESD Protection Devices



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.090	.107	2.30	2.70	
B	.063	.071	1.60	1.80	
C	.045	.053	1.15	1.35	
D	.031	.045	0.80	1.15	
E	.010	.016	0.25	0.40	
G	.004	.018	0.10	0.45	
H	.004	.010	0.10	0.25	
J	-----	.006	-----	0.15	

#### SUGGESTED SOLDER PAD LAYOUT





**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Reverse stand-off voltage	$V_{RWM}$				5	V
Reverse Breakdown voltage	$V_{BR}$	$I_t = 1\text{mA}$	6			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 5\text{V}$ $T=25^\circ\text{C}$			1	$\mu\text{A}$
Clamping Voltage	$V_C$	$I_{PP} = 1\text{A}$ $t_p = 8/20\mu\text{s}$			9.8	V
Clamping Voltage	$V_C$	$I_{PP} = 42\text{A}$ $t_p = 8/20\mu\text{s}$			13.5	V
Junction Capacitance	$C_j$	$V_R = 0\text{V}$ $f = 1\text{MHz}$			35	pF

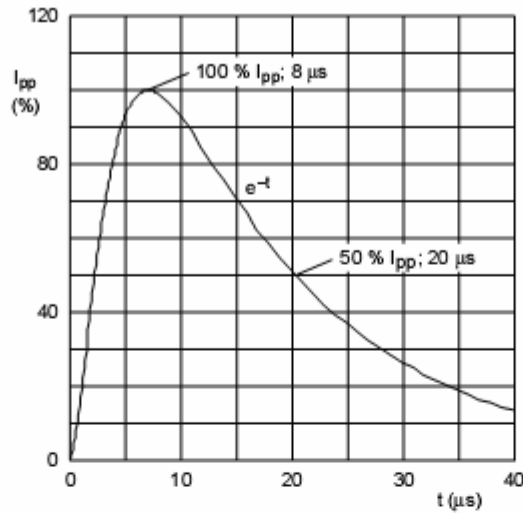


Figure 1. 8/20us pulse waveform

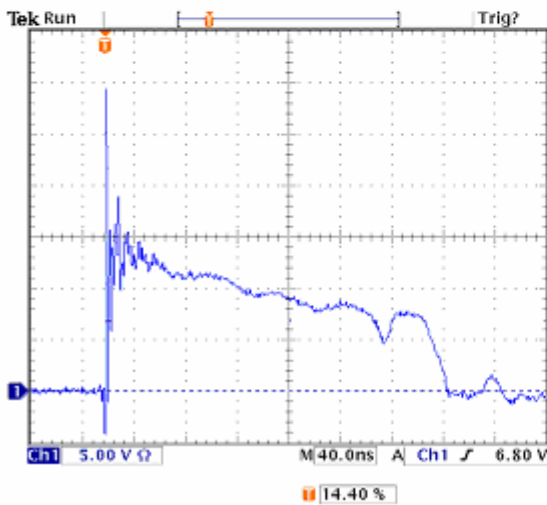


Figure 2 . Positive 8 kV Contact per IEC 6100-4-2

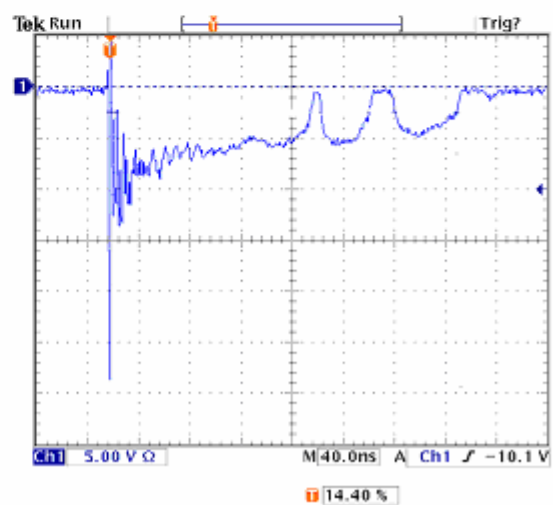


Figure 3. Negative 8 kV Contact per IEC 6100-4-2